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NTE74HC123 Integrated Circuit TTL – High Speed CMOS, Dual Retriggerable Monostable Multivibrator w/Resets

Description:

The NTE74HC123 is a dual monostable multivibrator with resets in a 16-Lead plastic DIP type package triggered by a negative to positive reset pulse. An external resistor (R_X) and an external capacitor (C_X) control the timing and the accuracy for the circuit. Adjustment of R_X and C_X provides a wide range of output pulse widths from the Q and \bar{Q} terminals. Pulse triggering on the \bar{A} and B inputs occur at a particular voltage level and is not related to the rise and fall times of the trigger pulses.

Once triggered, the output pulse width may be extended by retriggering inputs \bar{A} and B. The output pulse can be terminated by a LOW level on the Reset (R) pin. Trailing edge triggering (\bar{A}) and leading edge triggering (B) inputs are provided for triggering from either edge of the input pulse. If either Mono is no used each input on the unused device (\bar{A} , B, and \bar{R}) must be terminated high or low.

The minimum value of external resistance, R_X , is typically 5k Ω . The minimum value external capacitance, C_X , is 0pF. The calculation for the pulse width is $t_W = 0.45 R_X C_X$ at $V_{CC} = 5V$.

Features:

- Overriding Reset Terminates Output Pulse
- Triggering from the Leading or Trailing Edge
- Q and \bar{Q} Buffered Outputs
- Separate Resets
- Wide Range of Output Pulse Widths
- Schmitt Trigger on Both \bar{A} and B Inputs
- Fanout (Over Temperature Range):
 - Standard Outputs 10 LS-TTL Loads
 - Bus Driver Outputs 15 LS-TTL Loads
- Balanced Propagation Delay and Transition Times
- Significant Power Reduction Compared to LS-TTL Logic ICs

Absolute Maximum Ratings: (Note 1, Note 2)

Supply Voltage, V_{CC}	-0.5 to +7.0V
Clamp Diode Current, I_{IK}, I_{OK}	$\pm 20mA$
DC Output Current (Per Pin), I_{OUT}	$\pm 25mA$
DC V_{CC} or GND Current (Per Pin), I_{CC}	$\pm 50mA$
Maximum Junction Temperature, T_J	+150°C
Storage Temperature Range, T_{stg}	-65°C to +150°C
Typical Thermal Resistance, Junction-to-Ambient (Note 3), R_{thJA}	67°C/W
Lead Temperature (During Soldering, 10sec), T_L	+300°C

Note 1. Stresses above those listed in “Absolute Maximum Ratings” may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

Note 2. Unless otherwise specified, all voltages are referenced to GND.

Recommended Operating Conditions:

Parameter	Symbol	Min	Typ	Max	Unit	
Supply Voltage	V_{CC}	2.0	-	6.0	V	
DC Input or Output Voltage	V_{IN}, V_{OUT}	0	-	V_{CC}	V	
Operating Temperature Range	T_A	-55	-	+125	°C	
Input Rise or Fall Times $V_{CC} = 2.0V$	t_r, t_f	-	-	1000	ns	
		$V_{CC} = 4.5V$	-	-	500	ns
		$V_{CC} = 6.0V$	-	-	400	ns

DC Electrical Characteristics:

Parameter	Symbol	Test Conditions	V_{CC} (V)	+25°C			-40° to +85°C		-55° to +125°C		Unit			
				Min	Typ	Max	Min	Max	Min	Max				
High Level Input Voltage	V_{IH}		2.0	1.5	-	-	1.5	-	1.5	-	V			
			4.5	3.15	-	-	3.15	-	3.15	-	V			
			6.0	4.2	-	-	4.2	-	4.2	-	V			
Low Level Input Voltage	V_{IL}		2.0	-	-	0.5	-	0.5	-	0.5	V			
			4.5	-	-	1.35	-	1.35	-	1.35	V			
			6.0	-	-	1.8	-	1.8	-	1.8	V			
High Level Output Voltage CMOS Loads	V_{OH}	$V_{IN} = V_{IH} \text{ or } V_{IL},$ $I_O = -0.02mA$	2.0	1.9	-	-	1.9	-	1.9	-	V			
			4.5	4.4	-	-	4.4	-	4.4	-	V			
			6.0	5.9	-	-	5.9	-	5.9	-	V			
			TTL Loads	$V_I = V_{IH}$ or V_{IL}	$I_O = -4mA$	4.5	3.98	-	-	3.84	-	3.7	-	V
$I_O = -5.2mA$	6.0	5.48			-	-	5.34	-	5.2	-	V			
Low Level Output Voltage CMOS Loads	V_{OL}	$V_{IN} = V_{IH} \text{ or } V_{IL},$ $I_O = 0.02mA$	2.0	-	-	0.1	-	0.1	-	0.1	V			
			4.5	-	-	0.1	-	0.1	-	0.1	V			
			6.0	-	-	0.1	-	0.1	-	0.1	V			
			TTL Loads	$V_{IN} = V_{IH}$ or V_{IL}	$I_O = 4mA$	4.5	-	-	0.26	-	0.33	-	0.4	V
					$I_O = -5.2mA$	6.0	-	-	0.26	-	0.33	-	0.4	V
Input Leakage Current	I_{IN}	$V_{IN} = V_{CC} \text{ or } GND$	6.0	-	-	±0.1	-	±1.0	-	±1.0	µA			
Quiescent Device Current	I_{CC}	$V_{IN} = V_{CC} \text{ or } GND,$ $I_O = 0mA$	6.0	-	-	8.0	-	80	-	160	µA			

Prerequisite for Switching Characteristics:

Parameter	Symbol	Test Conditions	V_{CC} (V)	+25°C			-40° to +85°C		-55° to +125°C		Unit
				Min	Typ	Max	Min	Max	Min	Max	
Minimum Input, Pulse Width \bar{A}	t_{WL}		2.0	100	-	-	125	-	150	-	ns
			4.5	20	-	-	25	-	30	-	ns
			6.0	17	-	-	21	-	26	-	ns

Prerequisite for Switching Characteristics (Cont'd):

Parameter	Symbol	Test Conditions	V _{CC} (V)	+25°C			-40° to +85°C		-55° to +125°C		Unit
				Min	Typ	Max	Min	Max	Min	Max	
Minimum Input, Pulse Width B	t _{WH}		2.0	100	-	-	125	-	150	-	ns
			4.5	20	-	-	25	-	30	-	ns
			6.0	17	-	-	21	-	26	-	ns
Minimum Input, Pulse Width \bar{R}	t _{WL}		2.0	100	-	-	125	-	150	150	ns
			4.5	20	-	-	25	-	30	30	ns
			6.0	17	-	-	21	-	26	26	ns
\bar{A} and B Hold Time	t _H		2.0	50	-	-	65	-	75	75	ns
			4.5	10	-	-	13	-	15	15	ns
			6.0	9	-	-	11	-	13	13	ns
Reset Removal Time	t _{REM}		2.0	50	-	-	65	-	75	75	ns
			4.5	10	-	-	13	-	15	15	ns
			6.0	9	-	-	11	-	13	13	ns
Retrigger Time Number	t _{rT}	R _X = 10KΩ, C _X = 0, Note 3	5.0	-	50	-	63 (Typ)		76 (Typ)		ns
Output Pulse Width Q or \bar{Q}	t _W	R _X = 10KΩ, C _X = 10nF	5.0	40	-	50	38.7	51.3	38.2	51.8	μs

Note 3. Time to trigger depends on the values of R_X and C_X. The output pulse width can only be extended when the time between the active-going edges of the trigger input pulses meet the minimum retrigger time requirement.

Switching Characteristics: (t_r = t_f = 6ns, R_X = 10ΩK, C_X = 0 unless otherwise specified)

Parameter	Symbol	Test Conditions	V _{CC} (V)	+25°C			-40° to +85°C		-55° to +125°C		Unit
				Min	Typ	Max	Min	Max	Min	Max	
Trigger Propagation Delay, \bar{A} , B, \bar{R} to Q	t _{PLH}	C _L = 50pF	2.0	-	-	300	-	375	-	450	ns
			4.5	-	-	60	-	75	-	90	ns
			5.0	-	25	-	-	-	-	-	ns
			6.0	-	-	51	-	64	-	76	ns
Trigger Propagation Delay, \bar{A} , B, \bar{R} to \bar{Q}	t _{PHL}	C _L = 50pF	2.0	-	-	320	-	400	-	480	ns
			4.5	-	-	64	-	80	-	96	ns
			5.0	-	26	-	-	-	-	-	ns
			6.0	-	-	54	-	68	-	82	ns
Reset Propagation Delay, \bar{R} to Q or \bar{Q}	t _{PHL} , t _{PLH}	C _L = 50pF	2.0	-	-	215	-	270	-	325	ns
			4.5	-	-	43	-	54	-	65	ns
			6.0	-	-	37	-	46	-	55	ns
Output Transition Times	t _{TLH} , t _{THL}	C _L = 50pF	2.0	-	-	75	-	95	-	110	ns
			4.5	-	-	15	-	19	-	22	ns
			6.0	-	-	13	-	16	-	19	ns
Output Pulse Width		R _X = 10KΩ, C _X = 10nF	5.0	-	45	-	-	-	-	μs	
Pulse Width Match Between Circuits in the Same Package		R _X = 10KΩ, C _X = 10nF	5.0	-	±2	-	-	-	-	-	%

Switching Characteristics (Cont'd): ($t_r = t_f = 6\text{ns}$, $R_X = 10\Omega\text{K}$, $C_X = 0$ unless otherwise specified)

Parameter	Symbol	Test Conditions	V _{CC} (V)	+25°C			-40° to +85°C		-55° to +125°C		Unit
				Min	Typ	Max	Min	Max	Min	Max	
Input Capacitance	C _{IN}	C _L = 50pF	-	10	-	10	-	10	-	10	pF
Power Dissipation Capacitance	C _{PD}	C _L = 15pF, Note 4	5.0	-	-	-	-	-	-	-	pF

Note 4. C_{PD} is used to determine the dynamic power consumption, per multivibrator.
 $P_D = (C_{PD} + C_X) V_{CC}^2 f_I + \Sigma (C_L V_{CC}^2 f_O)$ where f_I = input frequency, f_O = output frequency, C_L = output load capacitance, C_X = external capacitance, V_{CC} = supply voltage, assuming $f_I \ll 1 / t_W$.

Truth Table:

Inputs			Output	
\bar{A}	B	\bar{R}	Q	\bar{Q}
H	X	H	L	H
X	L	H	L	H
L	↑	H		
↓	H	H		
X	X	L	L	H
L	H	↑		

H = High Voltage Level
 L = Low Voltage Level
 X = Don't Care

Pin Connection Diagram



